



# CLARE

**CPC1016N**  
4 Pin SOP OptoMOS® Relay



	<b>CPC1016N</b>	<b>Units</b>
Load Voltage	100	V
Load Current	100	mA
Max R <sub>ON</sub>	16	Ω

## Features

- Small 4 Pin SOP Package
- Low Drive Power Requirements (TTL/CMOS Compatible)
- No Moving Parts
- High Reliability
- Arc-Free With No Snubbing Circuits
- 1500V<sub>RMS</sub> Input/Output Isolation
- No EMI/RFI Generation
- Machine Insertable, Wave Solderable
- Tape & Reel Version Available

## Applications

- Instrumentation
  - Multiplexers
  - Data Acquisition
  - Electronic Switching
  - I/O Subsystems
  - Meters (Watt-Hour, Water, Gas)
- Medical Equipment—Patient/Equipment Isolation
- Security Systems
- Aerospace
- Industrial Controls
- Reed Relay Replacement

## Description

CPC1016N is a miniature low voltage, low on resistance 1-Form-A solid state relay in a 4 pin SOP package. The relay uses optically coupled MOSFET technology to provide 1500V of input to output isolation. The efficient MOSFET switches and photovoltaic die use Clare's patented OptoMOS® architecture. The optically-coupled input is controlled by a highly efficient GaAlAs infrared LED. The CPC1016N uses Clare's state of the art double molded vertical construction packaging to produce the world's smallest relay. The CPC1016N is ideal for replacing larger less reliable reed and electromechanical relays.

## Approvals

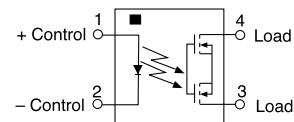
- UL Recognized Component  
File #: E76270
- Certified to: EN 60950

## Ordering Information

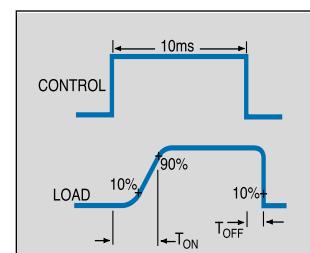
Part #	Description
CPC1016N	4 Pin SOP (100/tube)
CPC1016NTR	4 Pin SOP (2,000/reel)

## Pin Configuration

**CPC1016N Pinout**



## Switching Characteristics of Normally Open (Form A) Devices



**Absolute Maximum Ratings (@ 25° C)**

Parameter	Min	Typ	Max	Units
Input Power Dissipation	-	-	70	mW
Input Control Current Peak (10ms)	-	-	50	mA
Reverse Input Voltage	-	-	5	V
Total Power Dissipation	-	-	400 <sup>1</sup>	mW
Capacitance Input to Output	-	1	-	pF
Isolation Voltage Input to Output	1500	-	-	V <sub>RMS</sub>
Operational Temperature	-40	-	+85	°C
Storage Temperature	-40	-	+125	°C
Soldering Temperature (10 Seconds Max.)			+220	°C

1 Derate Linearly 3.33 mw / °C

*Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and effect its reliability.*

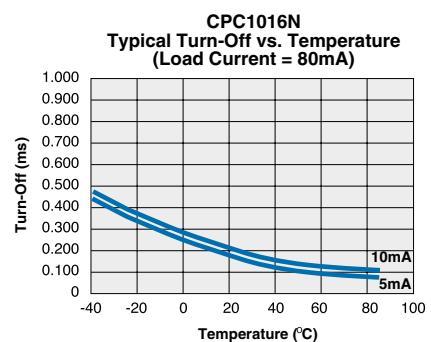
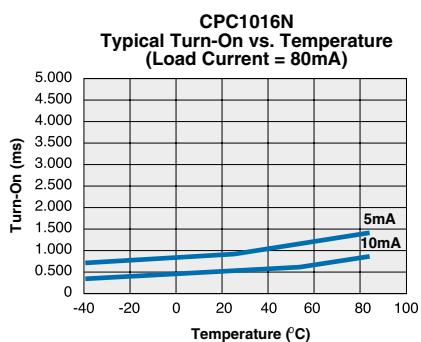
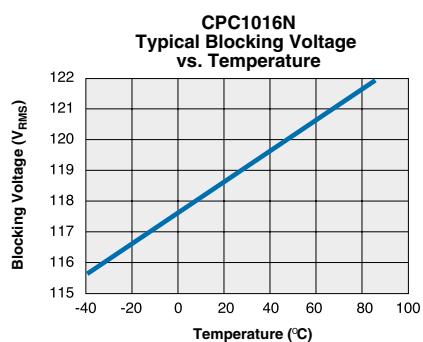
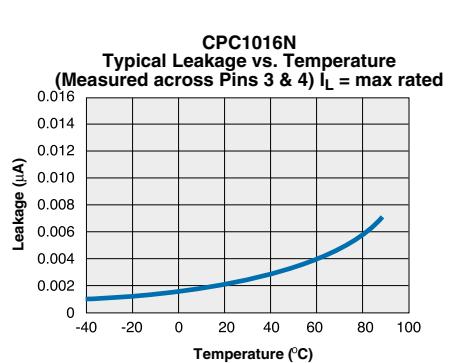
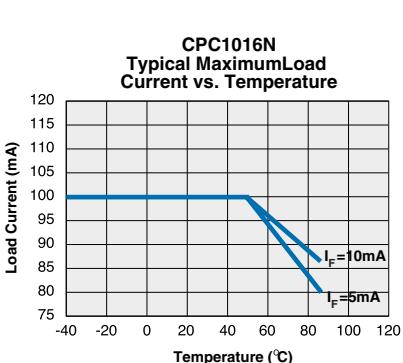
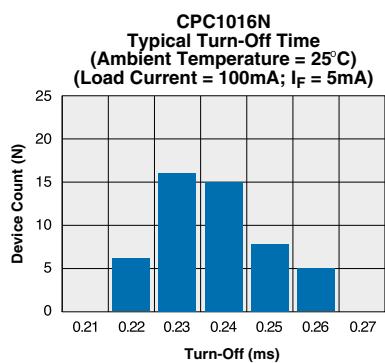
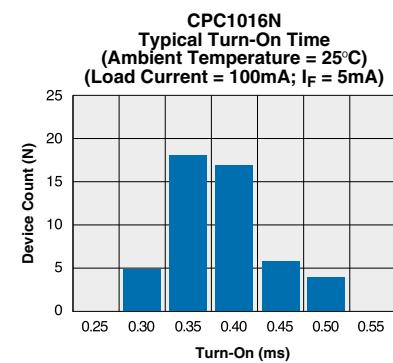
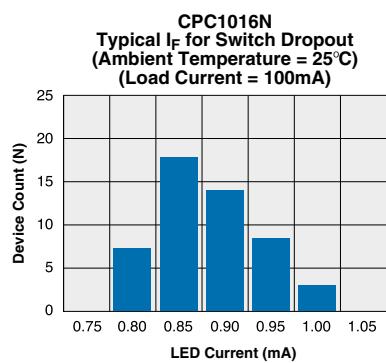
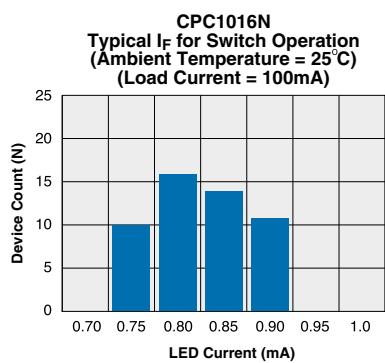
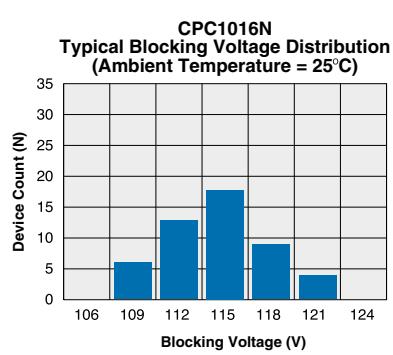
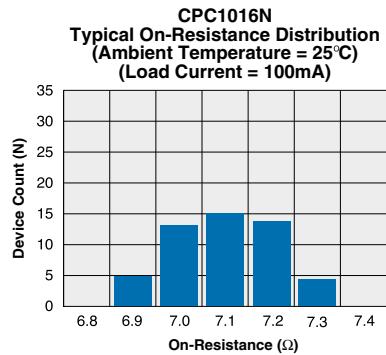
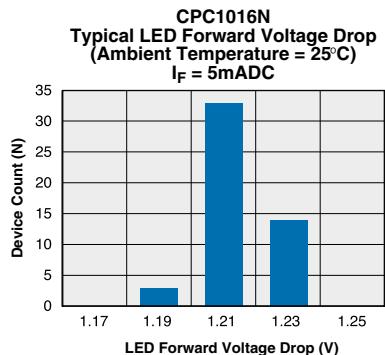
**Electrical Characteristics**

Parameter	Conditions	Symbol	Min	Typ	Max	Units
<b>Output Characteristics @ 25°C</b>						
Load Voltage (Peak)	-	V <sub>L</sub>	-	-	100	V
Load Current (Continuous) <sup>1</sup>		I <sub>L</sub>	-	-	100	mA
Peak Load Current	10ms	I <sub>LPK</sub>	-	-	350	mA
On-Resistance <sup>2</sup>	I <sub>L</sub> =100mA	R <sub>ON</sub>	-	-	16	Ω
Off-State Leakage Current	V <sub>L</sub> =100V	I <sub>LEAK</sub>	-	-	1	μA
Switching Speeds						
Turn-On	I <sub>F</sub> =5mA, V <sub>L</sub> =10V	T <sub>ON</sub>	-	-	2	ms
Turn-Off	I <sub>F</sub> =5mA, V <sub>L</sub> =10V	T <sub>OFF</sub>	-		0.5	ms
Output Capacitance	50V; f=1MHz	C <sub>OUT</sub>	-	25	-	pF
<b>Input Characteristics @ 25°C</b>						
Input Control Current	I <sub>L</sub> =100mA	I <sub>F</sub>	2	-	50	mA
Input Dropout Current	-	I <sub>F</sub>	0.3	0.9	-	mA
Input Voltage Drop	I <sub>F</sub> =5mA	V <sub>F</sub>	0.9	1.2	1.4	V
Reverse Input Voltage	-	V <sub>R</sub>	-	-	5	V
Reverse Input Current	V <sub>R</sub> =5V	I <sub>R</sub>	-	-	10	μA

1 Load current derates linearly from 100mA @ 25°C to approximately 120mA @ 85°C.

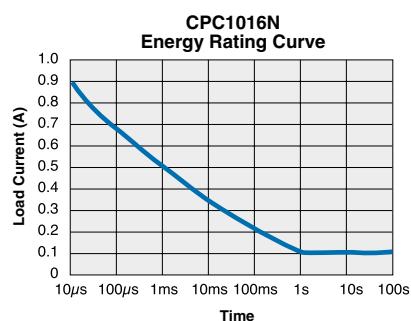
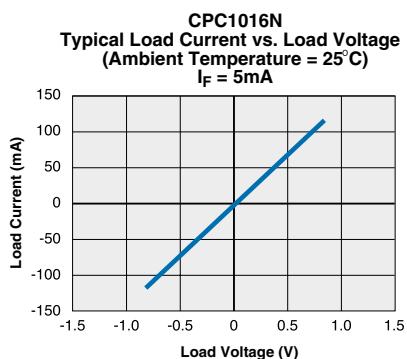
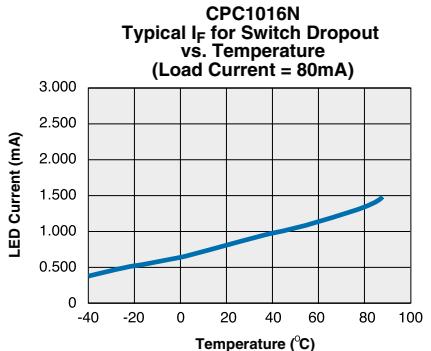
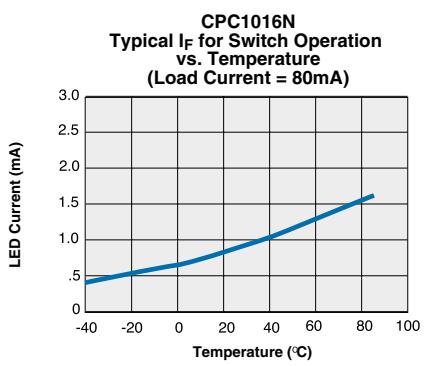
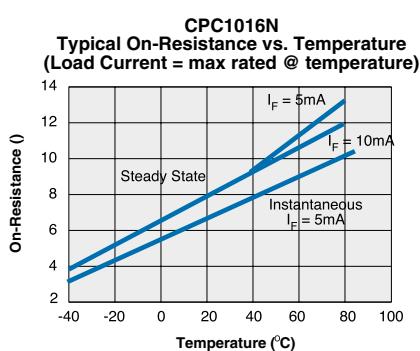
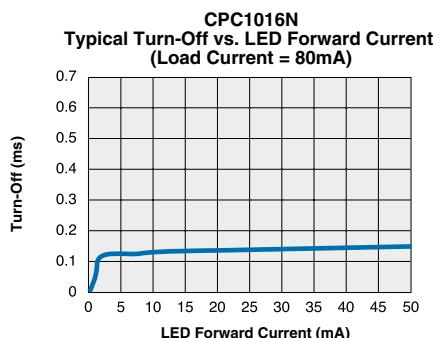
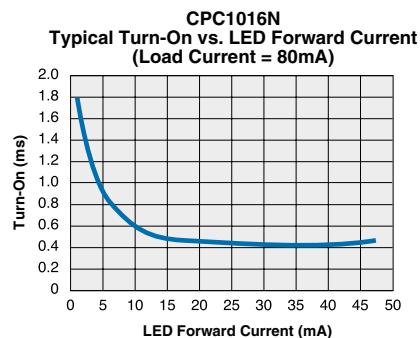
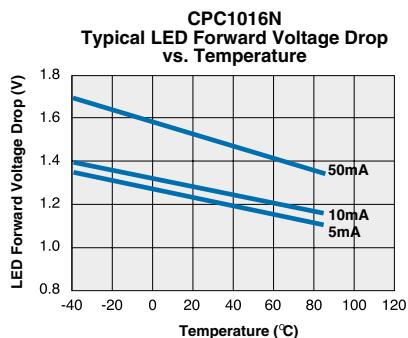
2 Measurement taken within 1 second of on time.

## PERFORMANCE DATA\*



\*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

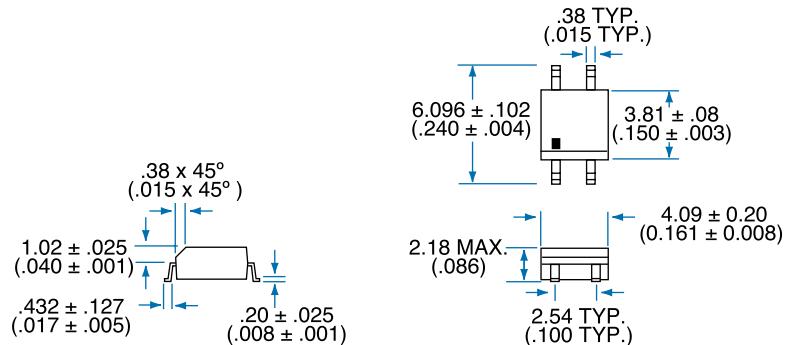
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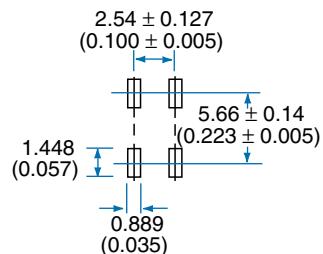
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### MECHANICAL DIMENSIONS

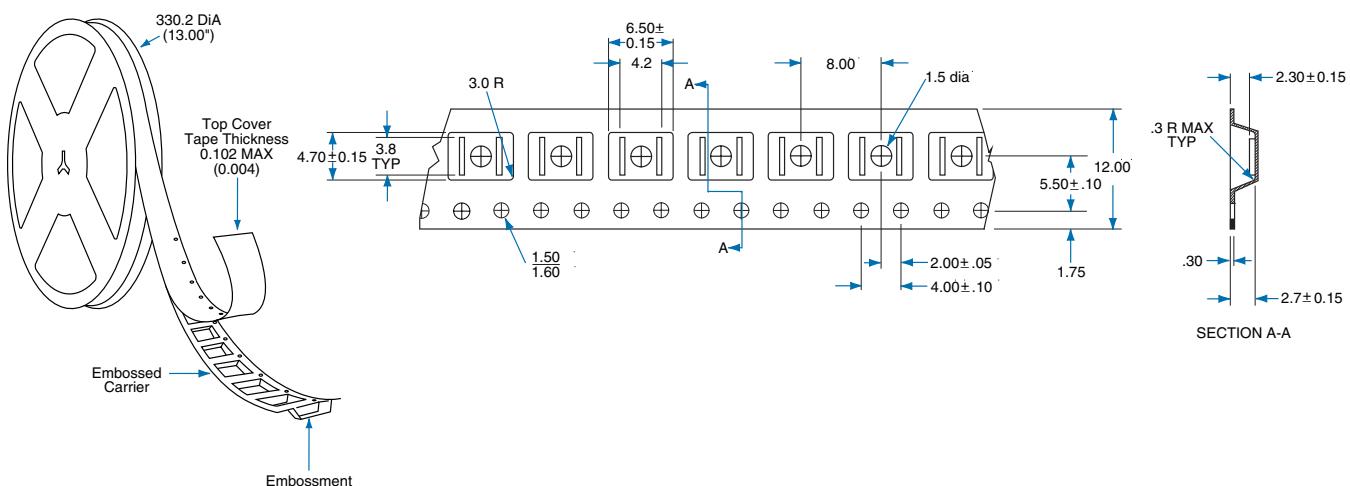
#### 4 Pin SOIC Narrow ("N" Suffix)



#### PC Board Pattern (Top View)



#### Tape and Reel Packaging for 4 pin SOIC package



Dimensions  
mm  
(inches)



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**For additional information please visit our website at: [www.clare.com](http://www.clare.com)**

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